SLLS044D - NOVEMBER 1988 - REVISED DECEMBER 1999

 μv_{cc}

GND

7 **|**] B

6 🛮 A

D OR P PACKAGE (TOP VIEW)

RE

DE [] 3

D

- Bidirectional Transceiver
- Meets or Exceeds the Requirements of TIA/EIA-422-B, TIA/EIA-485-A, and ITU Recommendation V.11
- High-Speed Advanced Low-Power Schottky Circuitry
- Low Skew . . . 6 ns Max
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- Low Supply-Current Requirements . . .
 30 mA Max
- Wide Positive and Negative Input/Output Bus-Voltage Ranges
- Driver Output Capacity . . . ±60 mA
- Thermal-Shutdown Protection
- Driver Positive and Negative Current Limiting
- Receiver Input Impedances . . . 12 kΩ Min
- Receiver Input Sensitivity . . . ±200 mV Max
- Receiver Input Hysteresis . . . 120 mV Typ
- Fail Safe . . . High Receiver Output With Inputs Open
- Operates From a Single 5-V Supply
- Glitch-Free Power-Up and Power-Down Protection
- Interchangeable With National DS3695 and DS3695A

description

The TL3695 differential bus transceiver is designed for bidirectional data communication on multipoint bus-transmission lines. It is designed for balanced transmission lines and meets TIA/EIA-422-B, TIA/EIA-485-A, and ITU Recommendation V.11.

The TL3695 combines a 3-state differential line driver and a differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can be externally connected together to function as a directional control. The driver differential outputs and the receiver differential inputs are connected internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus when the driver is disabled or $V_{\rm CC} = 0$. This port features wide positive and negative common-mode voltage ranges, making the device suitable for party line applications.

The TL3695 is characterized for operation from 0°C to 70°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



AVAILABLE OPTIONS

| | PACKAGED DEVICES | | | | | |
|-------------|------------------|-------------|--|--|--|--|
| TA | SMALL OUTLINE | PLASTIC DIP | | | | |
| | (D) | (P) | | | | |
| 0°C to 70°C | TL3695D | TL3695P | | | | |

The D package is available taped and reeled. Add the suffix R to device type (e.g., TL3695DR).

Function Tables

DRIVER

| INPUT | ENABLE | OUTI | PUTS |
|-------|--------|------|------|
| D | DE | Α | В |
| Н | Н | Н | L |
| L | Н | L | Н |
| X | L | Z | Z |

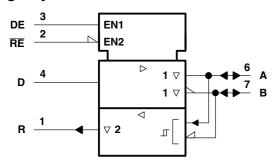
H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

RECEIVER

| DIFFERENTIAL INPUTS A – B | ENABLE RE | OUTPUT R |
|---|--------------|-------------|
| $V_{ID} \ge 0.2 \text{ V}$ | L | Н |
| $-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$ | L | ? |
| $V_{ID} \le -0.2 \text{ V}$ | L | L |
| X | Н | Z |
| Inputs open | L | Н |

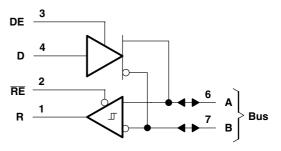
H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

logic symbol†

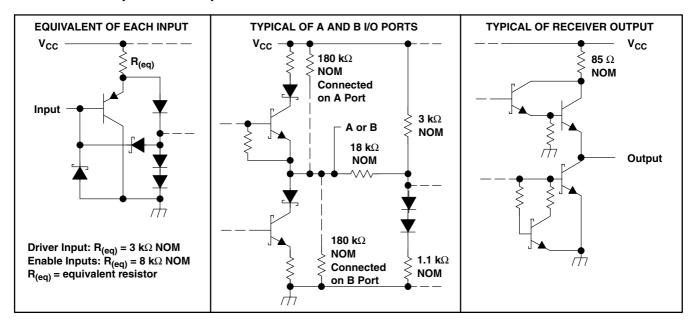


 † This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematic of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage, V _{CC} (see Note 1) | 7 V |
|--|----------------|
| Voltage range at any bus terminal | –10 V to 15 V |
| Enable input voltage, V _I | 5.5 V |
| Operating free-air temperature range, T _A | 0°C to 70°C |
| Package thermal impedance, θ _{JA} (see Note 2): D package | 97°C/W |
| PW package | |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | 260°C |
| Storage temperature range, T _{stg} | –65°C to 150°C |

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

TL3695 DIFFERENTIAL BUS TRANSCEIVER

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recommended operating conditions

| | | MIN | NOM | MAX | UNIT |
|--|---------------|------|-----|-------|------|
| Supply voltage, V _{CC} | | 4.75 | 5 | 5.25 | ٧ |
| Nelhana at any hya tamainal (anayatah ay asaman mada) Man M | | | | 12 | V |
| Voltage at any bus terminal (separately or common mode), V_{I} or V_{IC} | | | | -7 | ٧ |
| High-level Input voltage, $V_{\rm IH}$ | D, DE, and RE | 2 | | | ٧ |
| Low-level Input voltage, V _{IL} | D, DE, and RE | | | 8.0 | V |
| Differential input voltage, V _{ID} (see Note 3) | | | | ±12 | V |
| High level colors a common I | Driver | | | - 60 | mA |
| High-level output current, I _{OH} | Receiver | | | - 400 | μΑ |
| Low book orders and the | Driver | | | 60 | A |
| Low-level output current, I _{OL} | Receiver | | | 8 | mA |
| Operating free-air temperature, T _A | | 0 | | 70 | °C |

NOTE 3: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.



DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

| PARAMETER | | TEST CON | MIN | TYP‡ | MAX | UNIT | |
|--------------------|---|---|---|---|-----|-----------|----|
| V _{IK} | Input clamp voltage | I _I = – 18 mA | | | | -1.5 | V |
| Vo | Output voltage | I _O = 0 | | 0 | | 6 | V |
| V _{OD1} | Differential output voltage | I _O = 0 | | 1.5 | | 5 | V |
| V _{OD2} | Differential output voltage | $R_L = 100 \Omega$, | See Figure 1 | 1/2 V _{OD1} or 2 [§] | | | ٧ |
| | | $R_L = 54 \Omega$, | See Figure 1 | 1.5 | 2.5 | 5 | V |
| V_{OD3} | Differential output voltage | $V_{test} = -7 \text{ V to } 12 \text{ V},$ | See Figure 2 | 1.5 | | 5 | V |
| Δ V _{OD} | Change in magnitude of differential output voltage¶ | | | | | ±0.2 | V |
| V _{OC} | Common-mode output voltage | $R_L = 54 \Omega$, | See Figure 1 | | | 3 | V |
| Δ V _{OC} | Change in magnitude of common-mode output voltage¶ | | | | | ±0.2 | V |
| Io | Output current | Output disabled, See Note 4 | $V_O = 12 \text{ V}$ $V_O = -7 \text{ V}$ | | | 1 -0.8 | mA |
| I _{IH} | High-level input current | V _I = 2.4 V | | | | 20 | μΑ |
| I _{IL} | Low-level input current | V _I = 0.4 V | | | | -200 | μΑ |
| | | V _O = -6 V | | | | -250 | |
| ١. | 0 | V _O = 0 | | | | -150 | |
| los | Short-circuit output current# | $V_O = V_{CC}$ | | | | 250 | mA |
| | | V _O = 8 V | | | | 250 | |
| | Committee accomment | Natari | Outputs enabled | | 23 | 50 | A |
| Icc | Supply current | No load | Outputs disabled | - | 19 | 35 | mA |

[†] The power-off measurement in TIA/EIA-422-B applies to disabled outputs only and is not applied to combined inputs and outputs.

NOTE 4: This applies for power on and power off. Refer to TIA/EIA-485-A for exact conditions. The TIA/EIA-422-B limit does not apply for a combined driver and receiver terminal.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature

| | PARAMETER | TES | T CONDITIONS | | MIN | TYP‡ | MAX | UNIT |
|--------------------|--------------------------------------|-------------------------------------|----------------------|--------------|-----|------|-----|------|
| t _{d(OD)} | Differential-output delay time | | | | | 8 | 22 | ns |
| | Skew ($ t_{d(ODH)} - t_{d(ODL)} $) | $C_{L1} = C_{L2} = 100 \text{ pF},$ | $R_L = 60 \Omega$, | See Figure 3 | | 1 | 8 | ns |
| t _{t(OD)} | Differential output transition time | | | | | 8 | 18 | ns |
| t _{PZH} | Output enable time to high level | C _L = 100 pF, | $R_L = 500 \Omega$, | See Figure 4 | | | 50 | ns |
| t _{PZL} | Output enable time to low level | C _L = 100 pF, | $R_L = 500 \Omega$, | See Figure 5 | | | 50 | ns |
| t _{PHZ} | Output disable time from high level | C _L = 15 pF, | $R_L = 500 \Omega$, | See Figure 4 | | 8 | 30 | ns |
| t_{PLZ} | Output disable time from low level | C _L = 15 pF, | $R_L = 500 \Omega$, | See Figure 5 | | 8 | 30 | ns |

[‡] All typical values are at V_{CC} = 5 V and T_A = 25°C.



[‡] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

 $[\]S$ The minimum V_{OD2} with a 100- Ω load is either 1/2 V_{OD1} or 2 V, whichever is greater.

 $[\]P \Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level to a low level

[#] Duration of the short circuit should not exceed one second for this test.

SYMBOL EQUIVALENTS

| DATA-SHEET PARAMETER | TIA/EIA-422-B | TIA/EIA-485-A |
|----------------------|--------------------------------------|---|
| V _O | V _{oa} , V _{ob} | V_{oa}, V_{ob} |
| V _{OD1} | V _o | V _o |
| V _{OD2} | $V_t (R_L = 100 \Omega)$ | $V_t (R_L = 54 \Omega)$ |
| V _{OD3} | | V _t (test termination measurement 2) |
| V _{test} | | V _{tst} |
| Δ V _{OD} | $ V_t - \overline{V}_t $ | $ V_t - \overline{V}_t $ |
| V _{OC} | V _{os} | V _{os} |
| Δ V _{OC} | $ V_{os} - \overline{V}_{os} $ | $ V_{os} - \overline{V}_{os} $ |
| Ios | I _{sa} , | |
| I _O | I _{xa} , I _{xb} | I _{ia} , I _{ib} |

RECEIVER SECTION

electrical characteristics over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST C | TEST CONDITIONS | | | MAX | UNIT |
|------------------|--|--|--|-------------------|----|------|------|
| V _{IT+} | Positive-going input threshold voltage | $V_0 = 2.7 V$, | $I_0 = -0.4 \text{ mA}$ | | | 0.2 | V |
| V_{IT-} | Negative-going input threshold voltage | $V_O = 0.5 V$, | I _O = 8 mA | -0.2 [‡] | | | V |
| V_{hys} | Hysteresis voltage (V _{IT+} -V _{IT-}) | V _{OC} = 0 | | | 70 | | mV |
| V _{IK} | Enable-input clamp voltage | $I_{I} = -18 \text{ mA}$ | | | | -1.5 | V |
| V _{OH} | High-level output voltage | V_{ID} = 200 mV or in I_{OH} = -400 μ A, | V_{ID} = 200 mV or inputs open, I_{OH} = -400 μ A, See Figure 6 | | | | ٧ |
| ., | | $V_{ID} = -200 \text{ mV},$ | I _{OL} = 16 mA | | | 0.5 | ., |
| V_{OL} | Low-level output voltage | See Figure 6 | $I_{OL} = 8 \text{ mA}$ | | | 0.45 | V |
| loz | High-impedance-state output current | $V_O = 0.4 \text{ V to } 2.4 \text{ V}$ | | | | ±20 | μΑ |
| | | Other input = 0, | V _I = 12 V | | | 1 | |
| IĮ | Line input current | See Note 5 | $V_I = -7 \text{ V}$ | | | -0.8 | mA |
| I _{IH} | High-level enable-input current | V _{IH} = 2.7 V | • | | | 20 | μΑ |
| I _{IL} | Low-level enable-input current | V _{IL} = 0.4 V | | | | -100 | μΑ |
| rį | Input resistance | | | 12 | | | kΩ |
| los | Short-circuit output current§ | V _O = 0 | | -15 | | -85 | mA |
| | Committee accomment | | Outputs enabled | | 23 | 50 | A |
| I _{CC} | Supply current | No load | Outputs disabled | | 19 | 35 | mA |

 $^{^{\}dagger}$ All typical values are at $V_{CC}=5$ V and $T_{A}=25^{\circ}C.$

NOTE 5: This applies for power on and power off. Refer to TIA/EIA-485-A for exact conditions.



[‡] The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet for common-mode input voltage and threshold voltage levels only.

[§] Duration of the short circuit should not exceed one second for this test.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature range, C_L = 15 pF

| | PARAMETER | TEST CONDITIONS | MIN | TYP† | MAX | UNIT |
|------------------|---|--|-----|------|-----|------|
| t _{PLH} | Propagation delay time, low- to high-level output | $V_{ID} = -1.5 \text{ V to } 1.5 \text{ V},$ | | 14 | 37 | ns |
| t _{PHL} | Propagation delay time, high- to low-level output | See Figure 7 | | 14 | 37 | ns |
| t _{PZH} | Output enable time to high level | Con Figure 0 | | 7 | 20 | ns |
| t_{PZL} | Output enable time to low level | See Figure 8 | | 7 | 20 | ns |
| t _{PHZ} | Output disable time from high level | Coo Figure 0 | | 7 | 16 | ns |
| t_{PLZ} | Output disable time from low level | See Figure 8 | | 8 | 16 | ns |

[†] All typical values are at V_{CC} = 5 V and T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION

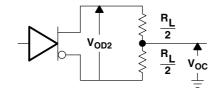


Figure 1. Driver V_{OD} and V_{OC}

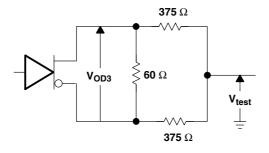
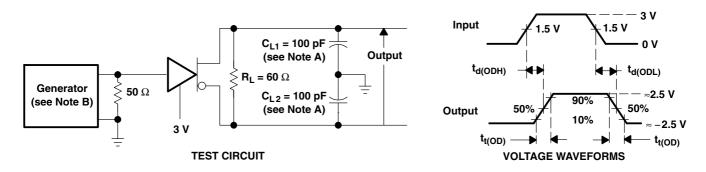


Figure 2. Driver V_{OD3}



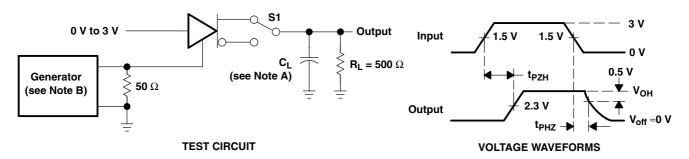
NOTES: A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_r \leq$ 6 ns, $t_f \leq$ 6 ns, $Z_O = 50 \Omega$.

Figure 3. Driver Differential-Output Test Circuit and Voltage Waveforms



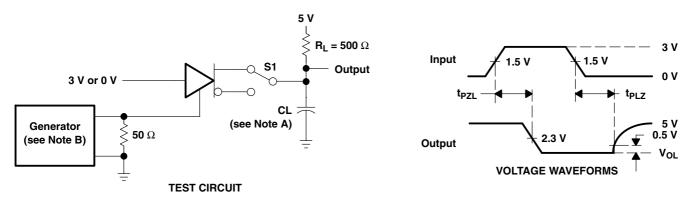
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns, $Z_O = 50 \ \Omega$.

Figure 4. Driver Test Circuit and Voltage Waveforms



NOTES: A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns, $Z_O =$ 50 Ω .

Figure 5. Driver Test Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION

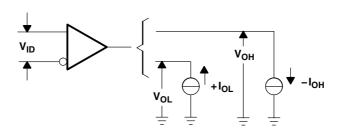
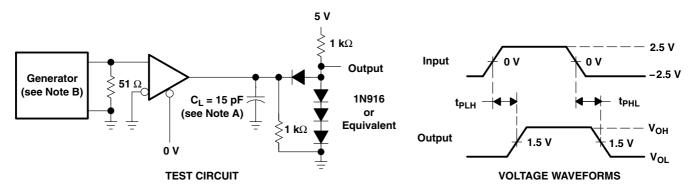


Figure 6. Receiver VOH and VOL

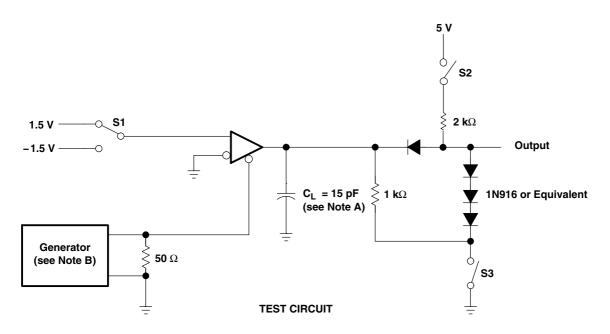


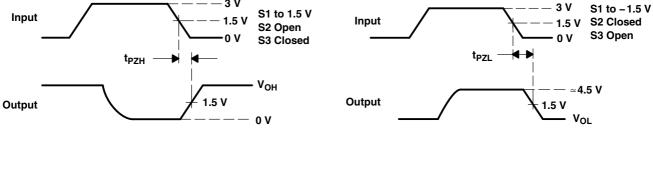
NOTES: A. C_L includes probe and jig capacitance.

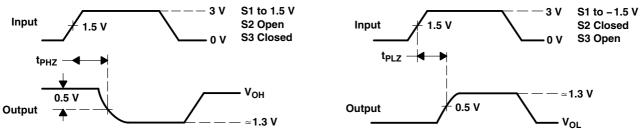
B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns, $Z_O =$ 50 Ω .

Figure 7. Receiver Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION







VOLTAGE WAVEFORMS

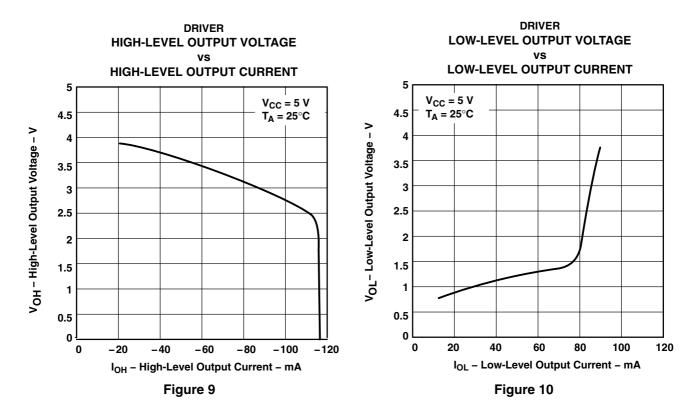
NOTES: A. C_L includes probe and jig capacitance.

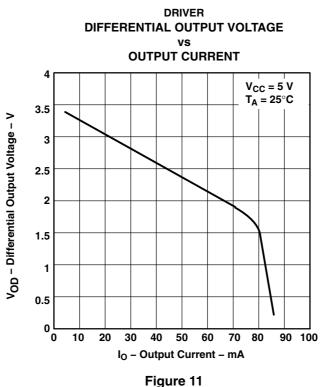
B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_r \leq$ 10 ns, $t_f \leq$ 10 ns, $Z_O =$ 50 Ω .

Figure 8. Receiver Test Circuit and Voltage Waveforms



TYPICAL CHARACTERISTICS†





[†] Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.



TYPICAL CHARACTERISTICS[†]

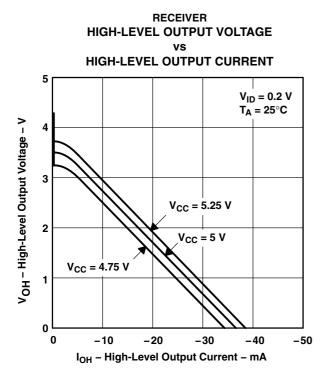
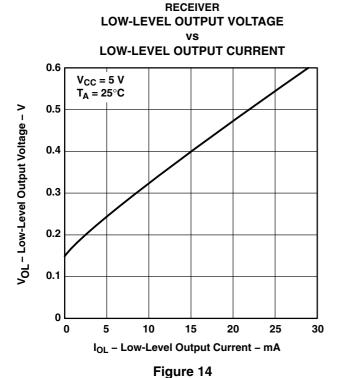


Figure 12



RECEIVER HIGH-LEVEL OUTPUT VOLTAGE vs FREE-AIR TEMPERATURE

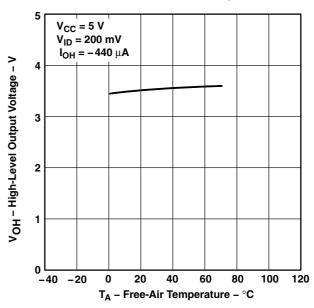


Figure 13

RECEIVER LOW-LEVEL OUTPUT VOLTAGE vs

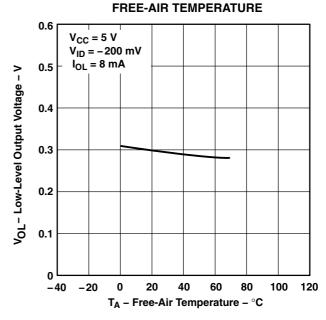
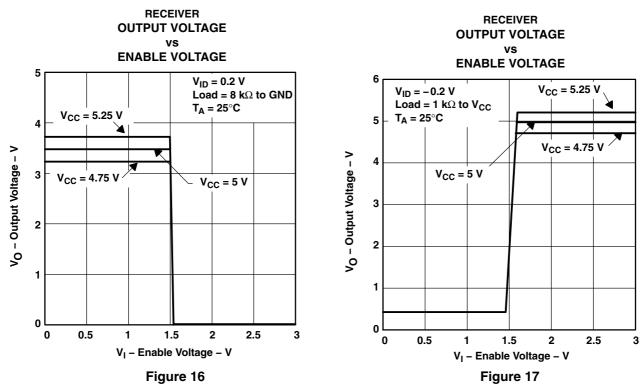


Figure 15

[†] Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

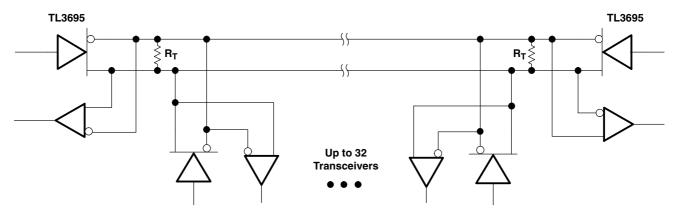


TYPICAL CHARACTERISTICS[†]



[†] Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

APPLICATION INFORMATION



NOTE A: The line should be terminated at both ends in its characteristic impedance ($R_T = Z_O$). Stub lengths off the main line should be kept as short as possible.

Figure 18. Typical Application Circuit







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PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | e Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|-----------------|--------------------|------|----------------|---------------------------|------------------|------------------------------|
| TL3695D | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TL3695DE4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TL3695DG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TL3695DR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TL3695DRE4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TL3695DRG4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| TL3695P | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |
| TL3695PE4 | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



TAPE AND REEL INFORMATION





| Α | 0 | Dimension designed to accommodate the component width |
|----|---|---|
| В | 0 | Dimension designed to accommodate the component length |
| | | Dimension designed to accommodate the component thickness |
| ٧ | ٧ | Overall width of the carrier tape |
| ГР | 1 | Pitch between successive cavity centers |

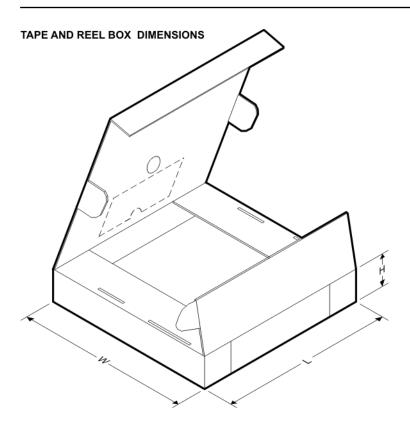
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------|------|--------------------|---|------|--------------------------|--------------------------|---------|---------|---------|------------|-----------|------------------|
| TL3695DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |





*All dimensions are nominal

| Device | Device Package Type | | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|----------|---------------------|---|------|------|-------------|------------|-------------|--|
| TL3695DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 | |

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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